

1. General description

Silicon Carbide Schottky diode in a DFN 8*8 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

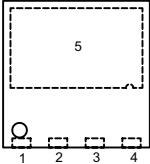
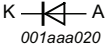
4. Quick reference data

Table 1. Quick reference data

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Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V _{RRM}	repetitive peak reverse voltage			650			V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _c ≤ 149 °C; Fig. 1 ; Fig. 2 ; Fig. 3		4			A
T _j	junction temperature			-55 to 175			°C
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 4 A; T _j = 25 °C; Fig. 5		-	1.45	1.70	V
		I _F = 4 A; T _j = 150 °C; Fig. 5		-	1.80	2.20	V
Dynamic characteristics							
Q _r	recovered charge	I _F = 4 A; dI _F /dt = 500 A/μs; V _R = 400 V; T _j = 25 °C; Fig. 7		-	6	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	n.c.	not connected		
3	A	anode		
4	A	anode		
5	K	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC5D04650T	DFN8*8	WNSC5D04650T6J	Tape	3000	DFN8X8N	25-Dec-2019

7. Marking

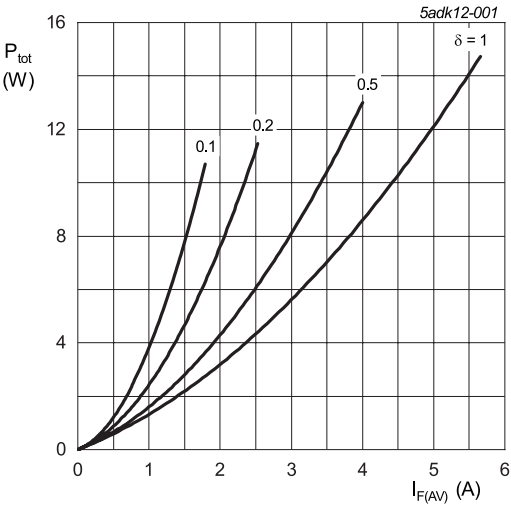
Table 4. Marking codes

Type number	Marking codes
WNSC5D04650T	WNSC5D 04650T

8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{RRM}	repetitive peak reverse voltage			650	V
V _{RWM}	crest working reverse voltage			650	V
V _R	reverse voltage	DC		650	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; T _c ≤ 149 °C; Fig. 1 ; Fig. 2 ; Fig. 3		4	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _c ≤ 149 °C; square-wave pulse		8	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse		28	A
		t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse		290	A
I ² t	I ² t for fusing	sine-wave pulse; T _{j(init)} = 25 °C; t _p = 10 ms		3.92	A ² s
T _{stg}	storage temperature			-55 to 175	°C
T _j	junction temperature			-55 to 175	°C



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$
$$V_o = 1.044 \text{ V}; R_s = 0.2758 \text{ } \Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

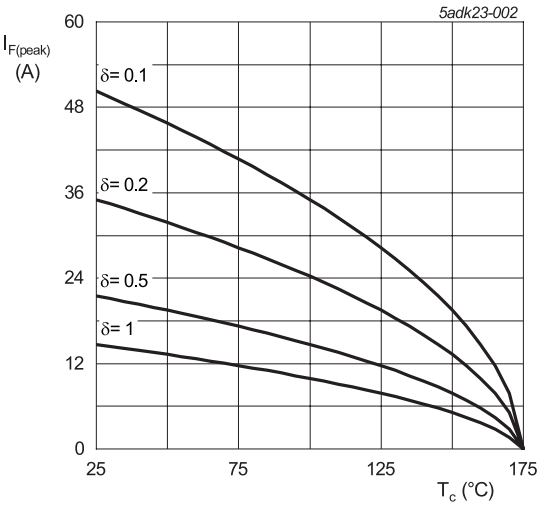


Fig. 2. Current derating as a function of case temperature

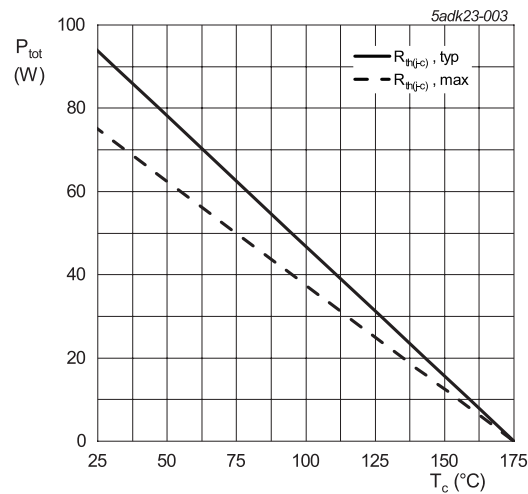


Fig. 3. Total power dissipation as a function of case temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	Fig. 4		-	1.6	2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W

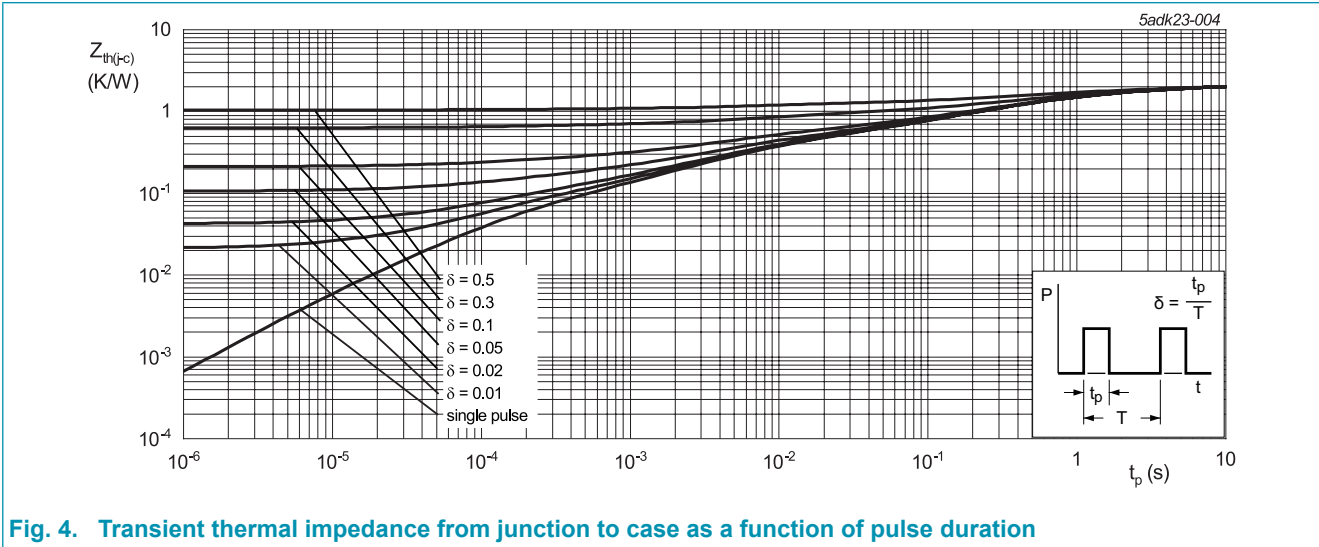
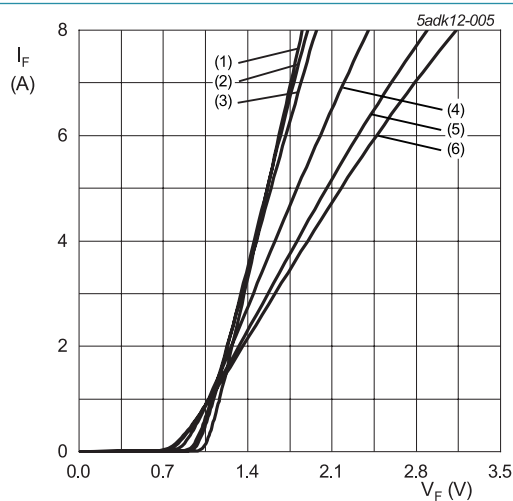


Fig. 4. Transient thermal impedance from junction to case as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _F	forward current	I _F = 4 A; T _j = 25 °C; Fig. 5		-	1.45	1.70	V
		I _F = 4 A; T _j = 150 °C; Fig. 5		-	1.80	2.20	V
		I _F = 4 A; T _j = 175 °C; Fig. 5		-	2.00	2.30	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; Fig. 6		-	0.2	20	μA
		V _R = 650 V; T _j = 175 °C; Fig. 6		-	10	100	μA
Dynamic characteristics							
Q _r	recovered charge	I _F = 4 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; Fig. 7		-	6	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	138	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C		-	17	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C		-	15	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 2.8 A; L = 5 mH; T _{j(init)} = 25 °C		20	-	-	mJ



V₀ = 1.044 V; R_s = 0.2758 Ω
(1) T_J = -55 °C; typical values
(2) T_J = 0 °C; typical values
(3) T_J = 25 °C; typical values
(4) T_J = 100 °C; typical values
(5) T_J = 150 °C; typical values
(6) T_J = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

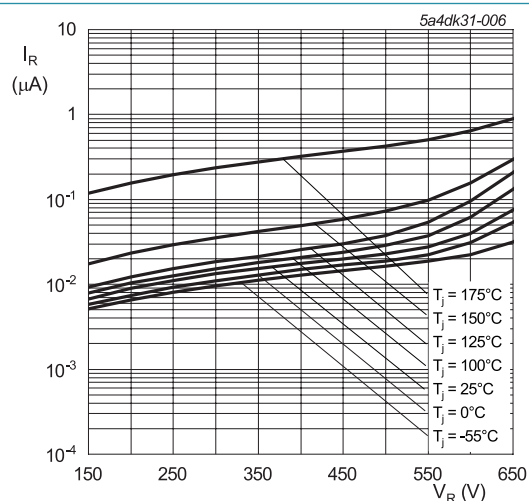


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

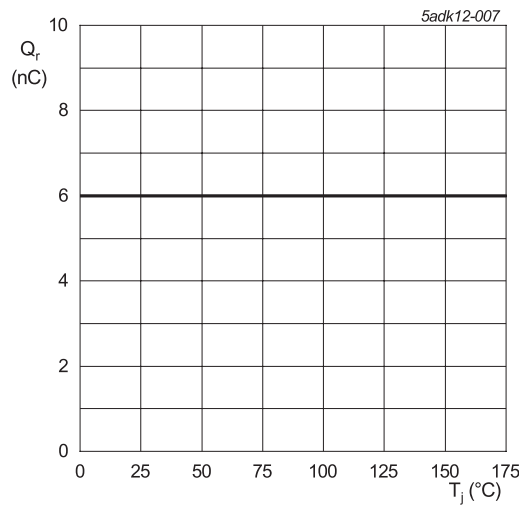
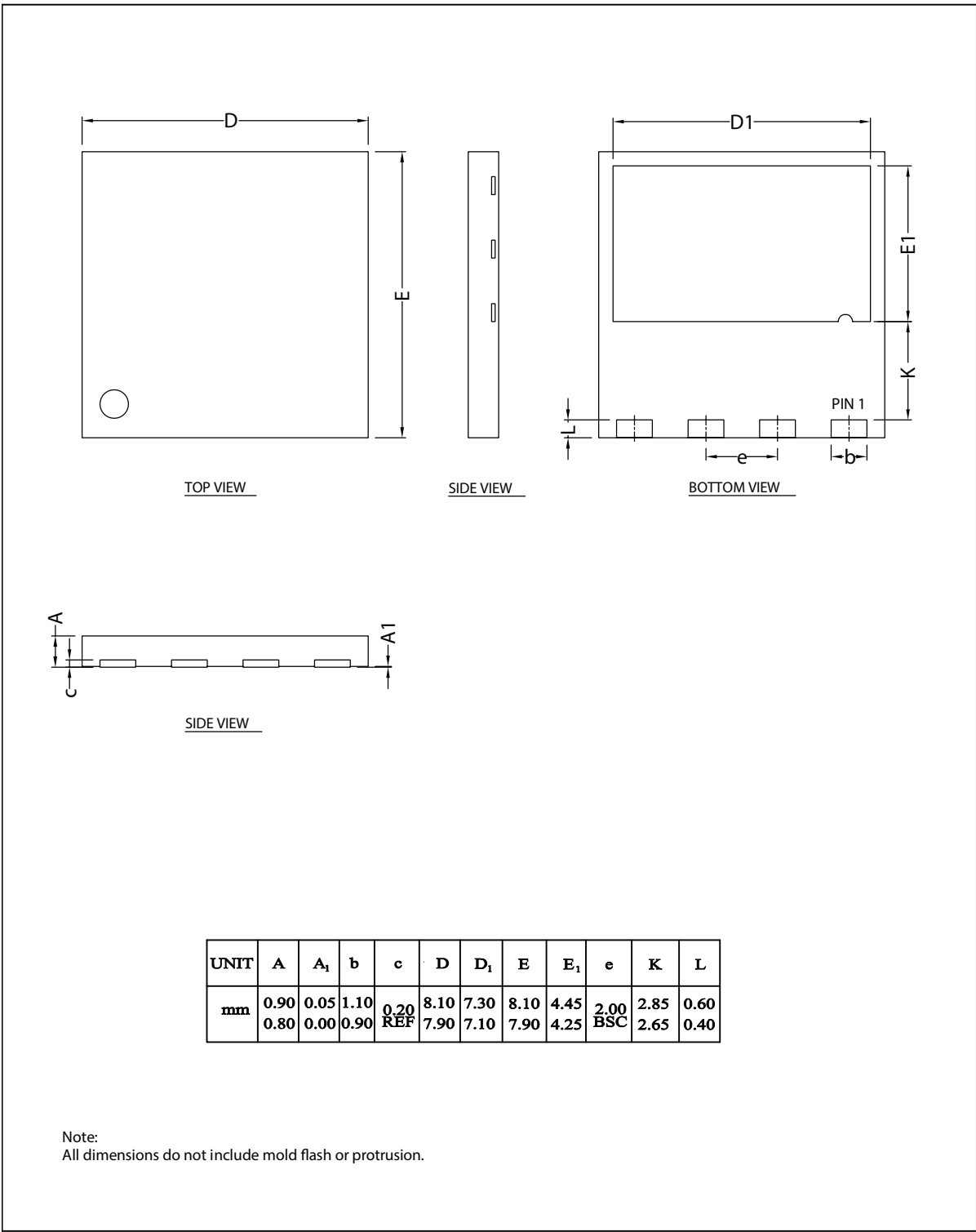


Fig. 7. Recovered charge as a function of junction temperature

11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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